

## Description:

Each OPB820 and OPB821Z device consists of an infrared emitting diode (LED, 890 nm center wavelength) and a NPN silicon phototransistor mounted in a low-cost black plastic housing on opposite sides of an 0.080 " (2.03 mm ) wide slot. Each device in this series has a $0.040^{\prime \prime}(1.02 \mathrm{~mm})$ wide aperture located in front of the infrared diode. Phototransistor switching occurs when an opaque object passes through the slot.

Devices are offered with $0.275^{\prime \prime}$ ( 6.96 mm ) lead spacing for PCBoard mounting (OPB820) or 24 " ( 609 mm ) 26 AWG wire leads (OPB821Z).

Custom electrical, wire and cabling and connectors are available. Contact your local representative or OPTEK for more information.

## Applications:

- Non-contact object sensing
- Assembly line automation
- Machine automation
- Equipment safety
- Machine safety

| Ordering Information |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Part Number | LED Peak Wavelength | Sensor | Slot Width I Depth | Aperture Emitter/Sensor | Lead Length / Spacing |
| OPB820 | 890 nm | Transistor | $\begin{aligned} & 0.080 "! \\ & 0.255 " \end{aligned}$ | 0.04"/ 0.04" | 0.425" / 0.275" |
| OPB820S10 |  |  |  | 0.04"/ 0.01" |  |
| OPB820S5 |  |  |  | 0.04"/ 0.005" |  |
| OPB820S3 |  |  |  | 0.04"/ 0.003" |  |
| OPB821Z |  |  |  | 0.040"/ 0.040" | 24"/26 AWGWire |
| OPB821S10Z |  |  |  | 0.040"/ 0.010" |  |
| OPB821S5Z |  |  |  | 0.040"/ 0.005" |  |
| OPB821S3Z |  |  |  | 0.040"/ 0.003" |  |

RoHS

## Package Drawing <br> OPB820



| Pin \# | Description | Pin \# | Description |
| :---: | :---: | :---: | :---: |
| 4 | Cathode | 2 | Collector |
| 3 | Anode | 1 | Emitter |



| Color/Pin \# | Description | Color/Pin \# | Description |
| :---: | :---: | :---: | :---: |
| Green-3 | Cathode | White-2 | Collector |
| Orange-4 | Anode | Blue-1 | Emitter |

OPTEK reserves the right to make changes at any time in order to improve design and to supply the best product possible.

## Slotted Optical Switch

## Absolute Maximum Ratings ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted)

| Storage and Operating Temperature | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| :--- | ---: |
| Lead Soldering Temperature (1/16 inch [1.6 mm] from case for 5 seconds with soldering iron) ${ }^{(1)}$ | $260^{\circ} \mathrm{C}$ |
| Input Diode |  |
| Continuous Forward Current | 50 mA |
| Peak Forward Current (1 $\mu \mathrm{m}$ pulse width, 300 pps$)$ | 1 A |
| Reverse Voltage | 2 V |
| Power Dissipation ${ }^{(2)}$ | 100 mW |

Output Phototransistor

| Collector-Emitter Voltage | 30 V |
| :--- | ---: |
| Emitter-Collector Voltage | 5 V |
| Power Dissipation $^{(2)}$ | 100 mW |

Notes:
(1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
(2) For OPB820, derate linearly $1.67 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $25^{\circ} \mathrm{C}$. For OPB821Z, derate linearly $1.82 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $25^{\circ} \mathrm{C}$.
(3) Methanol or isopropanol are recommended as cleaning agents. Plastic housing is soluble in chlorinated hydrocarbons and ketones.
(4) All parameters were tested using pulse technique.

Electrical Characteristics ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted)

| SYMBOL | PARAMETER | MIN | TYP | MAX | UNITS | TEST CONDITIONS |
| :---: | :--- | :---: | :---: | :---: | :---: | :---: |
| \begin{tabular}{\|c|l|c|c|c|c|c|}
\hline
\end{tabular} |  |  |  |  |  |  |
| \begin{tabular}{\|c|c|c|c|c|c|}
\hline
\end{tabular} |  |  |  |  |  |  |
| $\mathrm{I}_{\mathrm{F}}$ | Forward Voltage | Reverse Current | - | - | 1.7 | V |
| $\mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA}$ |  |  |  |  |  |  |

Output Phototransistor (See OP555 for additional information)

| $\mathrm{V}_{\text {(BR)CEO }}$ | Collector-Emitter Breakdown Voltage | 30 | - | - | V | $\mathrm{I}_{\mathrm{C}}=100 \mathrm{~mA}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {(BR)ECO }}$ | Emitter-Collector Breakdown Voltage | 5 | - | - | V | $\mathrm{I}_{\mathrm{E}}=100 \mu \mathrm{~A}$ |
| $\mathrm{I}_{\text {ceo }}$ | Collector-Emitter Dark Current | - | - | 100 | nA | $\mathrm{V}_{C E}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=0, \mathrm{I}_{\mathrm{E}}=0$ |
| Coupled |  |  |  |  |  |  |
| $V_{\text {CE(SAT) }}$ | Collector-Emitter Saturation Voltage OPB820, OPB821Z <br> OPB820S3, OPB821S3Z <br> OPB820S5, OPB821S5Z <br> OPB820S10, OPB821S10Z |  | - | $\begin{aligned} & 0.4 \\ & 0.4 \\ & 0.4 \\ & 0.4 \end{aligned}$ | $\begin{aligned} & V \\ & V \\ & V \\ & V \end{aligned}$ | $\begin{aligned} & \mathrm{I}_{\mathrm{C}}=250 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{C}}=40 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{C}}=150 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{C}}=250 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA} \end{aligned}$ |
| $\mathrm{IC}_{\text {(ON })}$ | On-State Collector Current OPB820, OPB821Z OPB820S3, OPB821S3Z OPB820S5, OPB821S5Z OPB820S10, OPB821S10Z | $\begin{gathered} 500 \\ 60 \\ 300 \\ 400 \end{gathered}$ | - | - | $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CE}}=5 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA} \\ & \mathrm{~V}_{\mathrm{CE}}=5 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA} \\ & \mathrm{~V}_{\mathrm{CE}}=5 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA} \\ & \mathrm{~V}_{\mathrm{CE}}=5 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA} \end{aligned}$ |

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